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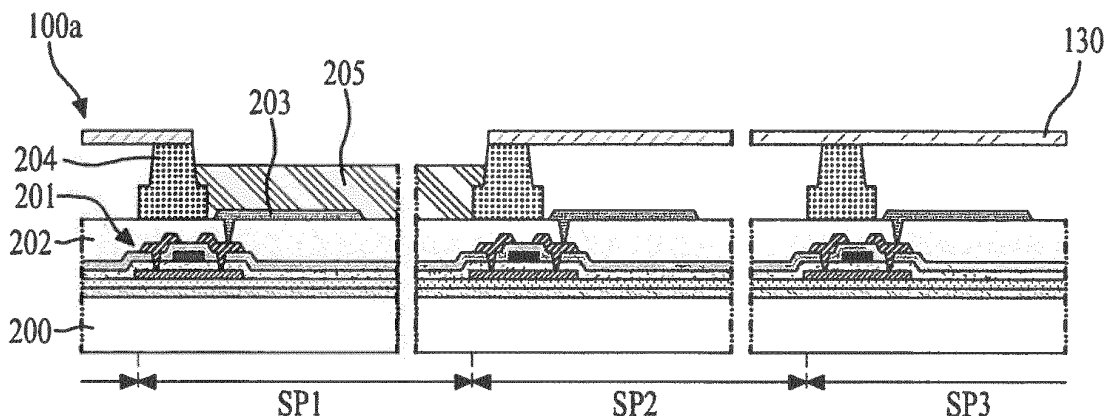
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(54) **Organic light emitting display device and method for manufacturing the same**

(57) Disclosed is a method of manufacturing an organic light emitting display device. The method include forming a driving thin film transistor and passivation layer on a substrate, forming a bank layer at a boundary portion between adjacent sub-pixels, on the passivation layer, laminating a first photoresist film on the bank layer, forming a first photoresist pattern by irradiating IR light on the first photoresist film in an area except a first sub-pixel, depositing a first organic emission layer in the first sub-

pixel area exposed by the first photoresist pattern, removing the first photoresist pattern, laminating a second photoresist film on the bank layer, forming a second photoresist pattern by irradiating IR light on the second photoresist film in an area except a second sub-pixel, depositing a second organic emission layer in the second sub-pixel area exposed by the second photoresist pattern, and removing the second photoresist pattern.

**FIG. 6**





EUROPEAN SEARCH REPORT

Application Number  
EP 13 16 8105

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X	US 2007/252525 A1 (SEKI SHUNICHI [JP]) 1 November 2007 (2007-11-01) * paragraph [0129] - paragraph [0163] *	15	ADD. B41M5/46
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A	ETIENNE MENARD ET AL: "Micro- and Nanopatterning Techniques for Organic Electronic and Optoelectronic Systems", CHEMICAL REVIEWS, AMERICAN CHEMICAL SOCIETY, WASHINGTON, DC, US, vol. 107, January 2007 (2007-01), pages 1117-1160, XP007911140, DOI: 10.1021/CRO50139Y [retrieved on 2007-11-04] * pages 1146-1148, chapter 4.2 *	7,9,10	
			TECHNICAL FIELDS SEARCHED (IPC)
			H01L G03F B41M
The present search report has been drawn up for all claims			
Place of search Munich		Date of completion of the search 10 December 2015	Examiner Bruckmayer, Manfred
CATEGORY OF CITED DOCUMENTS X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons ..... & : member of the same patent family, corresponding document	

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**ANNEX TO THE EUROPEAN SEARCH REPORT  
ON EUROPEAN PATENT APPLICATION NO.**

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For more details about this annex : see Official Journal of the European Patent Office, No. 12/82

专利名称(译)	有机发光显示装置及其制造方法		
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当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
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其他公开文献	EP2713399A2		
外部链接	<a href="#">Espacenet</a>		

摘要(译)

公开了一种制造有机发光显示装置的方法。该方法包括在基板上形成驱动薄膜晶体管 and 钝化层，在相邻子像素之间的边界部分处形成堤层，在钝化层上，在堤层上层叠第一光刻胶膜，形成第一光刻胶图案通过在除第一子像素之外的区域中的第一光刻胶膜上照射IR光，在由第一光刻胶图案暴露的第一子像素区域中沉积第一有机发光层，去除第一光刻胶图案，层压第二光刻胶膜在堤层上，通过在除第二子像素之外的区域中的第二光刻胶膜上照射IR光，在由第二光刻胶图案暴露的第二子像素区域中沉积第二有机发光层，形成第二光刻胶图案，以及去除第二光刻胶图案。

